

# SOT23 NPN SILICON PLANAR HIGH GAIN MEDIUM POWER TRANSISTOR

## FMMTL618

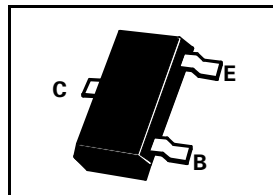
ISSUE 1 – NOVEMBER 1997

### FEATURES

Very low equivalent on-resistance;  $R_{CE(sat)}=140m\Omega$  at 1.25A

COMPLEMENTARY TYPE – FMMTL718

PARTMARKING DETAIL – L68



### ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	$V_{CEO}$	20	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Continuous Collector Current	$I_C$	1.25	A
Peak Pulse Current	$I_{CM}$	4	A
Base Current	$I_B$	200	mA
Power Dissipation at $T_{amb}=25^{\circ}C$	$P_{tot}$	500	mW
Operating and Storage Temperature Range	$T_j; T_{stg}$	-55 to +150	$^{\circ}C$

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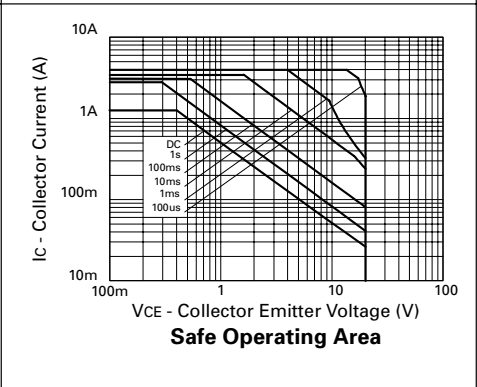
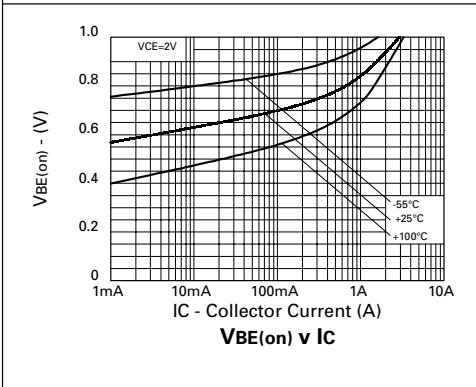
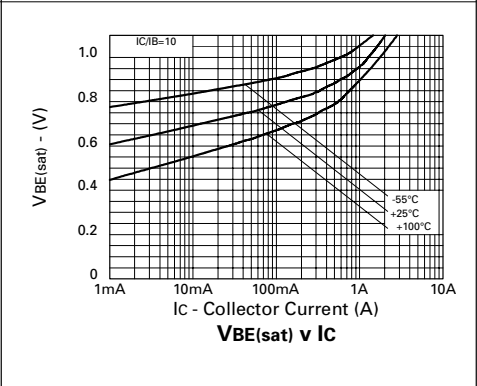
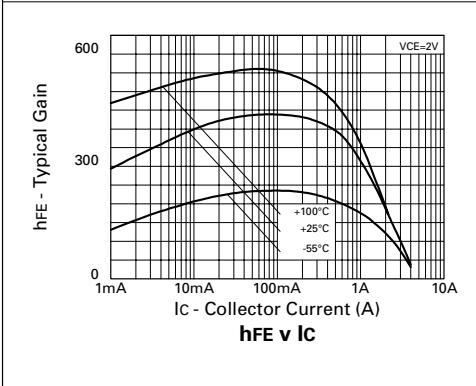
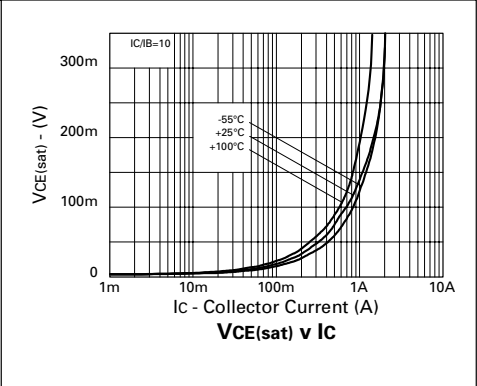
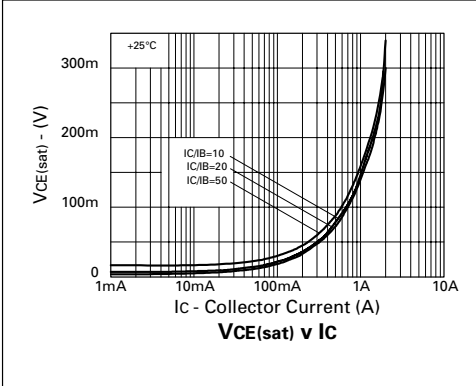
## ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ ).

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	60	105		V	$I_C=100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	20	30		V	$I_C=10\text{mA}^*$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5	8.5		V	$I_E=100\mu\text{A}$
Collector Cut-Off Current	$I_{CBO}$			10	nA	$V_{CE}=16\text{V}$
Emitter Cut-Off Current	$I_{EBO}$			10	nA	$V_{EB}=4\text{V}$
Collector Cut-Off Current	$I_{CES}$			10	nA	$V_{CE}=16\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		18 80 130 170 260	35 160 200 280 350	mV mV mV mV mV	$I_C=100\text{mA}, I_B=10\text{mA}^*$ $I_C=500\text{mA}, I_B=25\text{mA}^*$ $I_C=1\text{A}, I_B=100\text{mA}^*$ $I_C=1.25\text{A}, I_B=100\text{mA}^*$ $I_C=2\text{A}, I_B=200\text{mA}^*$
Base-Emitter Saturation Voltage	$V_{BE(sat)}$		1000	1100	mV	$I_C=1.25\text{A}, I_B=100\text{mA}^*$
Base-Emitter Turn On Voltage	$V_{BE(on)}$		850	1000	mV	$I_C=1.25\text{A}, V_{CE}=2\text{V}^*$
Static Forward Current Transfer Ratio	$h_{FE}$	200 300 250 200 100 50	400 440 400 300 190 100			$I_C=10\text{mA}, V_{CE}=2\text{V}$ $I_C=200\text{mA}, V_{CE}=2\text{V}^*$ $I_C=500\text{mA}, V_{CE}=2\text{V}^*$ $I_C=1\text{A}, V_{CE}=2\text{V}^*$ $I_C=2\text{A}, V_{CE}=2\text{V}^*$ $I_C=3\text{A}, V_{CE}=2\text{V}^*$
Transition Frequency	$f_T$		195		MHz	$I_C=50\text{mA}, V_{CE}=10\text{V}$ $f=100\text{MHz}$
Collector-Base Breakdown Voltage	$C_{obo}$		9	12	pF	$V_{CB}=10\text{V}, f=1\text{MHz}$
Switching times	$t_{on}$ $t_{off}$		72 388		ns ns	$I_C=1\text{A}, V_{CC}=10\text{V}$ $I_{B1}=-I_{B2}=10\text{mA}$

\*Measured under pulsed conditions. Pulse width=300 $\mu\text{s}$ . Duty cycle  $\leq 2\%$

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## TYPICAL CHARACTERISTICS



# AMEYA360

## Components Supply Platform

Authorized Distribution Brand :



Website :

Welcome to visit [www.ameya360.com](http://www.ameya360.com)

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd  
Minhang District, Shanghai , China

➤ Sales :

Direct +86 (21) 6401-6692

Email [amall@ameya360.com](mailto:amall@ameya360.com)

QQ 800077892

Skype [ameyasales1](#) [ameyasales2](#)

➤ Customer Service :

Email [service@ameya360.com](mailto:service@ameya360.com)

➤ Partnership :

Tel +86 (21) 64016692-8333

Email [mkt@ameya360.com](mailto:mkt@ameya360.com)